National Semiconductor LM193/LM293/LM393, LM193A/LM293A/LM393A, LM2903 Low Power Low Offset Voltage Dual Comparators General Description

The LM193 series consists of two independent precision voltage comparators with an offset voltage specification as low as 2.0 mV max for two comparators which were designed specifically to operate from a single power supply over a wide range of voltages. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage. These comparators also have a unique characteristic in that the input common-mode voltage range includes ground, even though operated from a single power supply voltage.

Application areas include limit comparators, simple analog to digital converters; pulse, squarewave and time delay generators; wide range VCO; MOS clock timers; multivibrators and high voltage digital logic gates. The LM193 series was designed to directly interface with TTL and CMOS. When operated from both plus and minus power supplies, the LM193 series will directly interface with MOS logic where their low power drain is a distinct advantage over standard comparators.

- Eliminates need for dual supplies
- Allows sensing near ground
- Compatible with all forms of logic
- Power drain suitable for battery operation

Features

	Wide single supply	
	Voltage range	2.0 V _{DC} to 36 V _{DC}
	or dual supplies	\pm 1.0 V _{DC} to \pm 18 V _{DC}
	Very low supply current drain of supply voltage	(0.4 mA) — independent
2	Low input biasing current	25 nA
••	Low input offset current	±5 nA
	and maximum offset voltage	±3 mV
•	Input common-mode voltage r	ange includes ground

- Differential input voltage range equal to the power supply voltage
- Low output saturation voltage, 250 mV at 4 mA
- Output voltage compatible with TTL, DTL, ECL, MOS and CMOS logic systems

Advantages

- High precision comparators
- Reduced V_{OS} drift over temperature



							Ľ	193/	LM29	3/LM3	33, L	M193	A/LM2	293A	VLM3	93A, LI	M2903
blute May ary/Aerospat t the National lifty and spec 0)	cimum Ratings e specified devices are required, p semiconductor Sales Office/Distributo fications.	olease rs foi		Operatin LM390 LM290 LM190	g Tei 3/LM 3/LM	nperatu 393A 293A 193A	re Range				- 25	*C to +	- 70°C - 85°C 125°C				
/oltage, V + tial Input Volta	36 V _{DC} or ±1 ge (Note 8) 3	8 VDC 16 VDC		Storage	U3 Temp	erature	Range	0000	laboot		- 65°	C to +	85°C 150°C				
oltage urrent (V _{IN} <	-0.3 V _{DC}) (Note 3)	16 VDC	~ -	Solderin Dual-I	g Info	rmation Packa	de de	0	lenino								
Dissipation (No ed DIP	te 1) 78	30 mV	_	Solc	Jering	(10 sec he Pack	conds) age						260°C				
Il Can Il Outline Packa	66 9e	0 mW		Vap Infra	or Ph ared (ase (60 15 seco	seconds) nds)						215°C 220°C				
: Short-Circuit to	Ground (Note 2) Conti	snonu		See AN- Reliabilit	450 '	Surfact	e Mountin nethods	of sol	dering	and Their surface m	Effec	t on Pr devices	oduct				
ctrical Ché	racteristics (V ⁺ = 5 V _{DC} , T _A = ,25	°C. ur	less o	therwise s	ng (1. tated)		series wit		pr)			-	2005				
			LM19	3A	L	293A, L	M393A		LM1	33	5	A293, L	M393		LM29	03	
arameter	Conditions	Min	Typ	Мах	Min	Typ	Мах	Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	Units
set Voltage	(Note 9)		±1.0	±2.0		± 1.0	±2.0		±1.0	±5.0		± 1.0	±5.0		±2.0	±7.0	mVpc
s Current	$I_{\rm IN}(+)$ or $I_{\rm IN}(-)$ with Output In Linear Range, V _{CM} = 0V (Note 5)		25	100		25	250		25	100		25	250		25	250	nApc
set Current	$l_{IN}(+) - l_{IN}(-) V_{CM} = 0V$		±3.0	±25		±5.0	±50		±3.0	±25		±5.0	±50		±5.0	±50	nApc
mmon Mode Range	V ⁺ = 30 V _{DC} (Note 6)	0		V+-1.5	0	-	/ ⁺ -1.5	0		V ⁺ -1.5	0	-	/ ⁺ -1.5	0		V ⁺ -1.5	Vbc
urrent	$R_L=\infty$ on All Comparators, $R_L=\infty$ on All Amps, V^+ = 36 V_{DC}		0.4 1	1 2.5		0.4 1	1 2.5		0.4	1 2.5		0.4	1 2.5		0.4 1	1.0 2.5	mADC mADC
Gain	R _L ≥15 kΩ, V ⁺ = 15 V _{DC} Vo = 1 V _{DC} to 11 V _{DC}	50	200		50	200		50	200		50	200		25	100		V/m/V
jnal Response	V_{IN} = TTL Logic Swing, V _{REF} = 1.4 V _{DC} V _{RL} = 5 V _{DC} , RL = 5.1 k Ω		300			300			300			300			300		su
e Time	$V_{RL} = 5 V_{DC}$, $R_L = 5.1 k\Omega$ (Note 7)		1.3			1.3			1.3			1.3			1.5		STI
ink Current	$V_{IN}(-) = 1 V_{DC}, V_{IN}(+) = 0, V_{O} \le 1.5 V_{DC}$	6.0	16		6.0	16		6.0	16		6.0	16		6.0	16		mApc
on Voltage	$V_{IN}(-) = 1 V_{DC}, V_{IN}(+) = 0, I_{SINK} \le 4 \text{ mA}$		250	400		250	400		250	400		250	400		250	400	mVpc
eakage Current	$V_{IN}(-) = 0, V_{IN}(+) = 1 V_{DC}, V_O = 5 V_{DC}$		0.1			0.1			0.1			0.1			0.1		nApc

			LMI	93A	LM29	3A,	LM393A		IM	93	M	293,	LM393		LM2	903	
	CONTRACTOR	Min	Тур	Max	Min	Гур	Max	Min	Υp	Max	Min	Гур	Max	Min	Гур	Max	Cinto
nput Offset Voltage	Note 9)			±4.0			±4.0			±9			÷9		÷9	±15	mVDC
nput Offset Current	IN(+) ⁻ I _{IN(-)} , V _{CM} =0V			±100			±150			±100			±150		± 50	±200	nApc
nput Bias Current	IN(+) or I _{IN} (-) with Output in Linear Range, / _{CM} =0V (Note 5)			300			400			300			400		200	500	nApc
nput Common Mode Voltage Range	/+=30 V _{DC} (Note 6)	0		V+-2.0	0		√+ -2.0	0		v+-2.0	0		V+-2.0	0		V+-2.0	VDC
aturation Voltage	$I_{IN}(-) = 1 V_{DC}, V_{IN}(+) = 0, I_{SINK} \le 4 \text{ mA},$			700			700			700			700		400	700	mVpc
Output Leakage Current	$V_{IN}(-)=0$, $V_{IN}(+)=1$ V _{DC} , V _O =30 V _{DC}			1.0			1.0			1.0			1.0			1.0	μApc
Differential Input Voltage	(eep All V _{IN} 's≥0 V _{DC} (or V ⁻ , if Used), Note 8)			36			36			36			36			36	V _{DC}
Note 2: Short circuits from the output to V ⁺ c: Note 3: This input current will only exist when clamps. In addition to this diode action, there is overdrive) for the time duration that an input is Note 4: These specifications are limited to -£ tions are limited to 0°C \leq T _A \leq + 70°C. The LM2	an cause excessive heating and eventual destruction. Wh the voltage at any of the input leads is driven negative, s also lateral NPN parasitic transistor action on the IC ch is driven negative. This is not destructive and normal out is driven negative. This is not destructive and normal out 57°C T _A S + 12°C, for the LM193/LM193A, With the LI 57°C T _A S + 12°C, for the LM193/LM193A, With the LI 2903 is limited to -40° C S T _A S + 85°C.	hen cor hip. Thi put sta M293/	nsideri lue to s tran: tes wi LM29;	ing short circ the collector sistor action ill re-establis 3A all tempe	uits to r-base can ca h whe rature	groun junctii luse th n the i specif	d, the maxin on of the inp le output vo nput voltage ications are	num or out PN Itages 3, whic limitec	of the h was	urrent is app sistors beco comparator negative, aç 25°C≤TA≤∽	roxima ming f s to go gain re + 85°C	orward to the turns the and t	0 mA indepe 1 biased and 3 V ⁺ voltage to a value gr he LM393/L	ndent thereb level eater t M393/	of the yy act (or to han - temp	ing as input ground for a -0.3 V _{DC} .	diode Large cifica-
tions are limited to $0^{\circ}C \le T_A \le + 70^{\circ}C$. The LM. Note 5: The direction of the input current is or Note 6: The input common-mode voltage or eif to 36 V _{DC} without damage, independent of the	2903 is limited to $-40^{\circ}C \le T_A \le +85^{\circ}C$. ut of the IC due to the PNP input stage. This current is e ther input signal voltage should not be allowed to go neg- e magnitude of V ⁺ .	essenti ative b	ally cc y more	onstant, inde ₂ than 0.3V.	pende The up	nt of t	he state of t nd of the cou	the out	put sc mode	no loading voltage rang	chang le is V	e exis + 1.	ts on the ref ⊽V at 25°C, t	erence out eith	orin		an go
Note 7: The response time specified is for a 1	100 mV input step with 5 mV overdrive. For larger overd	rive sig	inals 3	300 ns can b	e obta	tined,	see typical p	perform	lance	characterist	ics se	tion.			er or t	put lines. both inputs c	
Note 8: Positive excursions of input voltage mathematical not be less than $-0.3~V_{DC}$ (or 0.3 V_{DC} below	ay exceed the power supply level. As long as the other vo the magnitude of the negative power supply, if used).	oltage r		s within the	commo	on-mo	de range, th	e com	varato.	will nrovide	a pro	per ou	nut etato Th		er or t	put lines. both inputs c	
Note 9: At output switch point, $V_{O} \simeq 1.4~V_{DC},$ Note 10: Refer to RETS193AX for LM193AH/	$R_S = 0\Omega$ with V ⁺ from 5 V _{DC} to 30 V _{DC} ; and over the fu	ull inpl	emain					Vpc)		in provide			put state	ne low	er or t	put lines. poth inputs c voltage state	must

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Application Hints

The LM193 series are high gain, wide bandwidth devices which, like most comparators, can easily oscillate if the output lead is inadvertently allowed to capacitively couple to the inputs via stray capacitance. This shows up only during the output voltage transition intervals as the comparator change states. Power supply bypassing is not required to solve this problem. Standard PC board layout is helpful as it reduces stray input-output coupling. Reducing the input resistors to < 10 k Ω reduces the feedback signal levels and finally, adding even a small amount (1.0 to 10 mV) of positive feedback (hysteresis) causes such a rapid transition that oscillations due to stray feedback are not possible. Simply socketing the IC and attaching resistors to the pins will cause input-output oscillations during the small transition intervals unless hysteresis is used. If the input signal is a pulse waveform, with relatively fast rise and fall times, hysteresis is not required.

All pins of any unused comparators should be grounded.

The bias network of the LM193 series establishes a drain current which is independent of the magnitude of the power supply voltage over the range of from 2.0 V_{DC} to 30 V_{DC} .

It is usually unnecessary to use a bypass capacitor across the power supply line.

Typical Applications (Continued) (V+ = 15 V_{DC})

The differential input voltage may be larger than V⁺ without damaging the device (see Note 8). Protection should be provided to prevent the input voltages from going negative more than -0.3 V_{DC} (at 25°C). An input clamp diode can be used as shown in the applications section.

The output of the LM193 series is the uncommitted collector of a grounded-emitter NPN output transistor. Many collectors can be tied together to provide an output OR'ing function. An output pull-up resistor can be connected to any available power supply voltage within the permitted supply voltage range and there is no restriction on this voltage due to the magnitude of the voltage which is applied to the V+ terminal of the LM193 package. The output can also be used as a simple SPST switch to ground (when a pull-up resistor is not used). The amount of current which the output device can sink is limited by the drive available (which is independent of V⁺) and the β of this device. When the maximum current limit is reached (approximately 16 mA). the output transistor will come out of saturation and the output voltage will rise very rapidly. The output saturation voltage is limited by the approximately 600 rSAT of the output transistor. The low offset voltage of the output transistor (1.0 mV) allows the output to clamp essentially to ground level for small load currents.

Crystal Controlled Oscillator

















